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BLU6H0410L-600P; BLU6H0410LS-600P

Power LDMOS transistor

Rev. 3 — 1 September 2015

AMPLEON Product data sheet

1. Product profile

1.1 General description

A 600 W LDMOS RF power transistor for radar transmitter applications and industrial applications in the frequency range of 400 MHz to 900 MHz.

Table 1. Application information

Typical RF performance at V_{DS} = 50 V; in a common source 860 MHz narrowband test circuit; unless otherwise specified.

Test signal	f	I _{Dq}	P _{L(AV)}	P _{L(M)}	Gp	η_D	IMD3
	(MHz)	(mA)	(W)	(W)	(dB)	(%)	(dBc)
pulsed, class-AB [1]	860	1.3	-	600	20	58	-

[1] Measured at δ = 10 %; t_p = 1 ms.

1.2 Features and benefits

- Excellent ruggedness (VSWR ≥ 40 : 1 through all phases)
- Optimum thermal behavior and reliability, R_{th(i-c)} = 0.15 K/W
- High power gain
- High efficiency
- Internal input matching for high gain and optimum broadband operation
- Excellent reliability
- Easy power control
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

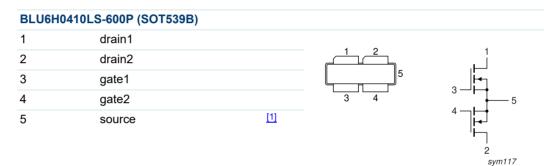
 Power amplifier for radar transmitter applications in the 400 MHz to 900 MHz frequency range

Power LDMOS transistor

2. Pinning information

Pin	Pinning Description	Simplified outline	Graphic symbol
	•	Simplified Outlifie	Oraphic Symbol
DLUONU	410L-600P (SOT539A)		
1	drain1		4
2	drain2		י لـــا
3	gate1		
4	gate2	3 4	
5	source	[1]	

| 2 *sym117*



[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLU6H0410L-600P	-	flanged balanced LDMOST ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLU6H0410LS-600P	-	earless flanged balanced LDMOST ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DS}	drain-source voltage		-	110	V
V _{GS}	gate-source voltage		-0.5	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

5. Thermal characteristics

Table 5.	Thermal characteristics						
Symbol	Parameter	Conditions		Тур	Unit		
R _{th(j-c)}	thermal resistance from junction to case	T _j = 150 °C	[1]	0.15	K/W		
Z _{th(j-c)}	transient thermal impedance from	T _j = 150 °C					
	junction to case	t_p = 100 μs; δ = 10 %		0.020	K/W		
		t_p = 200 μ s; δ = 10 %		0.023	K/W		
		t_p = 300 μ s; δ = 10 %		0.025	K/W		
		t_p = 500 μs; δ = 10 %		0.028	K/W		
		t_p = 100 μ s; δ = 20 %		0.035	K/W		

[1] $R_{th(j-c)}$ is measured under RF conditions.

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I _D = 2.4 mA	[1]	110	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I _D = 240 mA	[1]	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 50 V		-	-	2.8	μA
I _{DSX}	drain cut-off current	$\label{eq:VGS} \begin{array}{l} V_{GS} = V_{GS(th)} + 3.75 \; V; \\ V_{DS} = 10 \; V \end{array}$		-	36	-	A
I _{GSS}	gate leakage current	V_{GS} = 10 V; V_{DS} = 0 V		-	-	280	nA
$R_{\text{DS(on)}}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 8.5 A	<u>[1]</u>	-	143	-	mΩ
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	[2]	-	220	-	pF
C _{oss}	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz		-	74	-	pF
C _{rss}	reverse transfer capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz		-	1.2	-	pF

[1] I_D is the drain current.

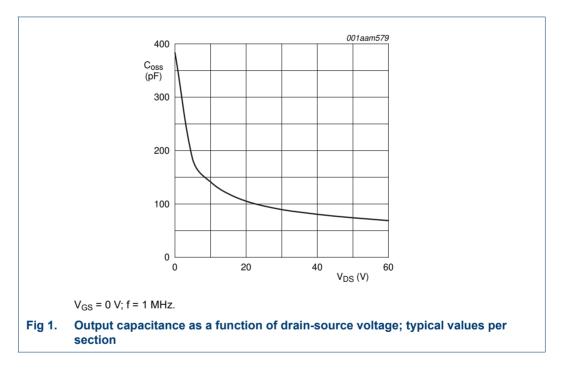
[2] Capacitance values without internal matching.

Table 7. RF characteristics

Test signal: 2-Tone; $T_{case} = 25 \ ^{\circ}C$ unless otherwise specified; in a class-AB Ampleon production narrowband test circuit.

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage			-	50	-	V
I _{Dq}	quiescent drain current		[1]	-	1.3	-	А
$P_{L(AV)}$	average output power	f ₁ = 860 MHz; f ₂ = 860.1 MHz		250	-	-	W
G _p	power gain	f ₁ = 860 MHz; f ₂ = 860.1 MHz		20	21	-	dB
η_D	drain efficiency	f ₁ = 860 MHz; f ₂ = 860.1 MHz		42	46	-	%
IMD3	third-order intermodulation distortion	f ₁ = 860 MHz; f ₂ = 860.1 MHz		-	-32	-28	dBc

[1] I_{Dq} for total device.



6.1 Ruggedness in class-AB operation

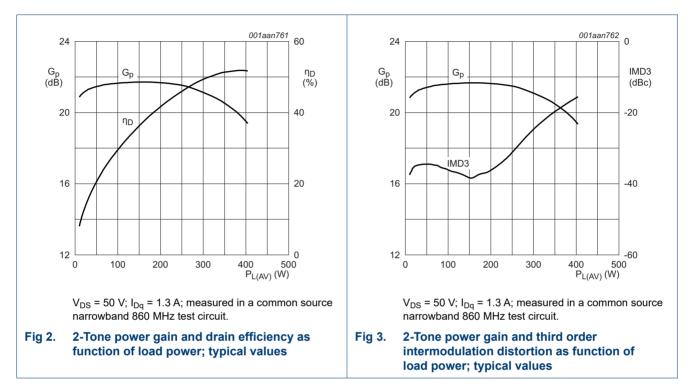
The BLU6H0410L-600P and BLU6H0410LS-600P are capable of withstanding a load mismatch corresponding to VSWR \geq 40 : 1 through all phases under the following conditions: V_{DS} = 50 V; f = 860 MHz at rated power.

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7. Application information

7.1 Narrowband RF figures

7.1.1 2-Tone



7.2 Impedance information

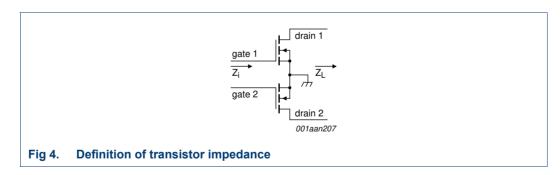


Table 8. Typical push-pull impedance

Simulated Z_i and Z_L device impedance; impedance info at $V_{DS} = 50$ V and $P_{L(M)} = 600$ W.

f	Z _i	ZL
MHz	Ω	Ω
300	0.617 – j1.715	4.989 + j1.365
325	0.635 – j1.355	4.867 + j1.424
350	0.655 – j1.026	4.741 + j1.472
375	0.677 – j0.721	4.614 + j1.511

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f	Zi	ZL
MHz	Ω	Ω
400	0.702 – j0.435	4.486 + j1.540
425	0.731 – j0.164	4.357 + j1.559
450	0.762 + j0.096	4.228 + j1.570
475	0.798 + j0.347	4.100 + j1.573
500	0.839 + j0.592	4.974 + j1.567
525	0.884 + j0.833	3.850 + j1.554
550	0.936 + j1.072	3.728 + j1.534
575	0.995 + j1.310	3.608 + j1.508
600	1.063 + j1.549	3.492 + j1.475
625	1.141 + j1.791	3.378 + j1.437
650	1.230 + j2.037	3.268 + j1.394
675	1.334 + j2.289	3.161 + j1.347
700	1.456 + j2.548	3.057 + j1.295
725	1.599 + j2.814	2.957 + j1.239
750	1.768 + j3.090	2.860 + j1.180
775	1.971 + j3.376	2.676 + j1.118
800	2.214 + j3.671	2.677 + j1.053
825	2.510 + j3.975	2.591 + j0.985
850	2.873 + j4.282	2.508 + j0.915
875	3.320 + j4.584	2.428 + j0.843
900	3.875 + j4.865	2.351 + j0.770
925	4.562 + j5.095	2.277 + j0.695
950	5.409 + j5.223	2.206 + j0.618
975	6.426 + j5.166	2.138 + j0.540
1000	7.587 + j4.807	2.073 + j0.461

Table 8. Typical push-pull impedance ... continued

Power LDMOS transistor

8. Test information

Table 9.List of components

For test circuit, see Figure 5, Figure 6 and Figure 7.

Component	Description	Value	I	Remarks
B1, B2	semi rigid coax	25 Ω; 49.5 mm	l	UT-090C-25 (EZ 90-25)
C1	multilayer ceramic chip capacitor	12 pF	<u>[1]</u>	
C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	8.2 pF	[1]	
C7	multilayer ceramic chip capacitor	6.8 pF	[2]	
C8	multilayer ceramic chip capacitor	2.7 pF	[2]	
C9	multilayer ceramic chip capacitor	2.2 pF	[2]	
C10, C13, C14	multilayer ceramic chip capacitor	100 pF	<u>[3]</u>	
C11, C12	multilayer ceramic chip capacitor	10 pF	[2]	
C15, C16	multilayer ceramic chip capacitor	4.7 μF; 50 V		Kemet C1210X475K5RAC-TU or capacitor of same quality.
C17, C18, C23, C24	multilayer ceramic chip capacitor	100 pF	[2]	
C19, C20	multilayer ceramic chip capacitor	10 μF; 50 V		TDK C570X7R1H106KT000N or capacitor of same quality.
C21, C22	electrolytic capacitor	470 μF; 63 V		
C30	multilayer ceramic chip capacitor	10 pF	<u>[4]</u>	
C31	multilayer ceramic chip capacitor	9.1 pF	<u>[4]</u>	
C32	multilayer ceramic chip capacitor	3.9 pF	<u>[4]</u>	
C33, C34, C35	multilayer ceramic chip capacitor	100 pF	<u>[4]</u>	
C36, C37	multilayer ceramic chip capacitor	4.7 μF; 50 V		TDK C4532X7R1E475MT020U or capacitor of same quality.
L1	microstrip	-	[5]	(W × L) 15 mm × 13 mm
L2	microstrip	-	[5]	(W \times L) 5 mm \times 26 mm
L3, L32	microstrip	-	[5]	(W \times L) 2 mm \times 49.5 mm
L4	microstrip	-	[5]	(W × L) 1.7 mm × 3.5 mm
L5	microstrip	-	[5]	(W \times L) 2 mm \times 9.5 mm
L30	microstrip	-	[5]	(W \times L) 5 mm \times 13 mm
L31	microstrip	-	[5]	(W \times L) 2 mm \times 11 mm
L33	microstrip	-	<u>[5]</u>	(W \times L) 2 mm \times 3 mm
R1, R2	wire resistor	10 Ω		
R3, R4	SMD resistor	5.6 Ω	(0805
R5, R6	wire resistor	100 Ω		
R7, R8	potentiometer	10 kΩ		

[1] American technical ceramics type 800R or capacitor of same quality.

[2] American technical ceramics type 800B or capacitor of same quality.

[3] American technical ceramics type 180R or capacitor of same quality.

[4] American technical ceramics type 100A or capacitor of same quality.

[5] Printed-Circuit Board (PCB): Taconic RF35; ε_r = 3.5 F/m; height = 0.762 mm; Cu (top/bottom metallization); thickness copper plating = 35 μ m.



-+V_{D1(test)}

+V_{D2(test)}

C23

+⊥____C21

÷

50 Ω

÷

001aan763

BLU6H0410L(S)-600P

Power LDMOS transistor



C13 📥

C14 📥

L3

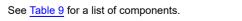
B1

C15

📥 C16

L4

C10



Class-AB common source broadband amplifier; V_{D1(test)}, V_{D2(test)}, V_{G1(test)} and V_{G2(test)} are drain and gate test voltages Fig 5.

-

C17 📥

C1

C18 📥

1

L30

L31

C31 C30

| C32

Ŧ

C19

R1

C5

=

11

C2

C3

= ≑ C4

R2

C20

÷

📥 C11

C8

C12

+ + =

C6 C7 L2

C9

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+V_{G1(test)}

R

R

R3

R4

R8

+VG2(test)

C33

C34

📥 C35

L33

L32

B2

50 Ω

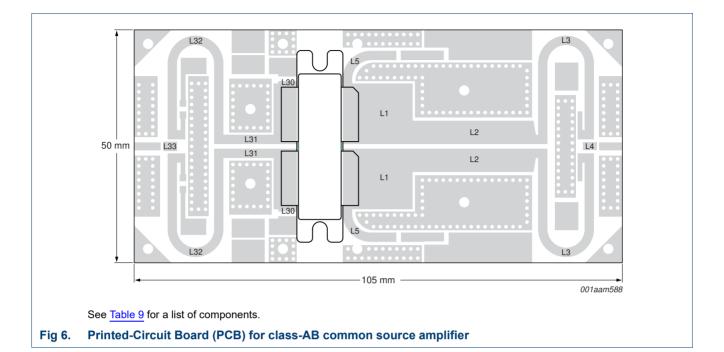
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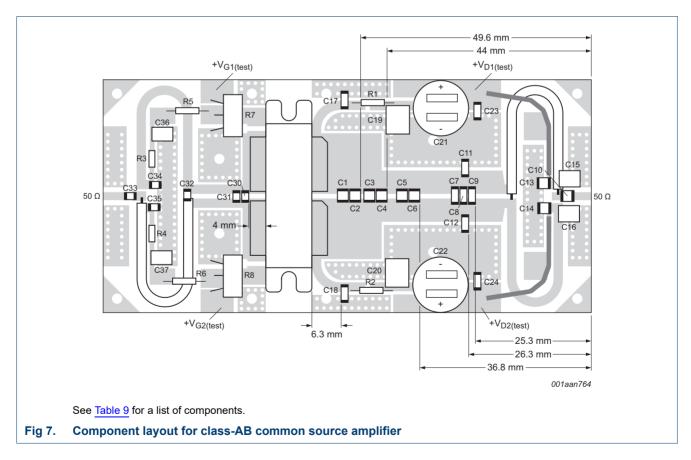
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BLU6H0410L(S)-600P

Power LDMOS transistor





Power LDMOS transistor

9. Package outline

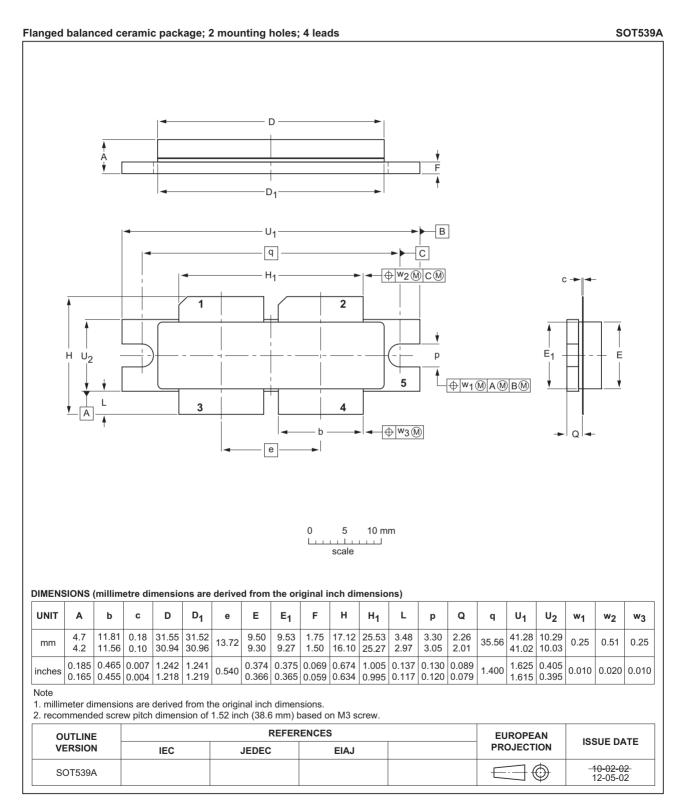


Fig 8. Package outline SOT539A

Power LDMOS transistor

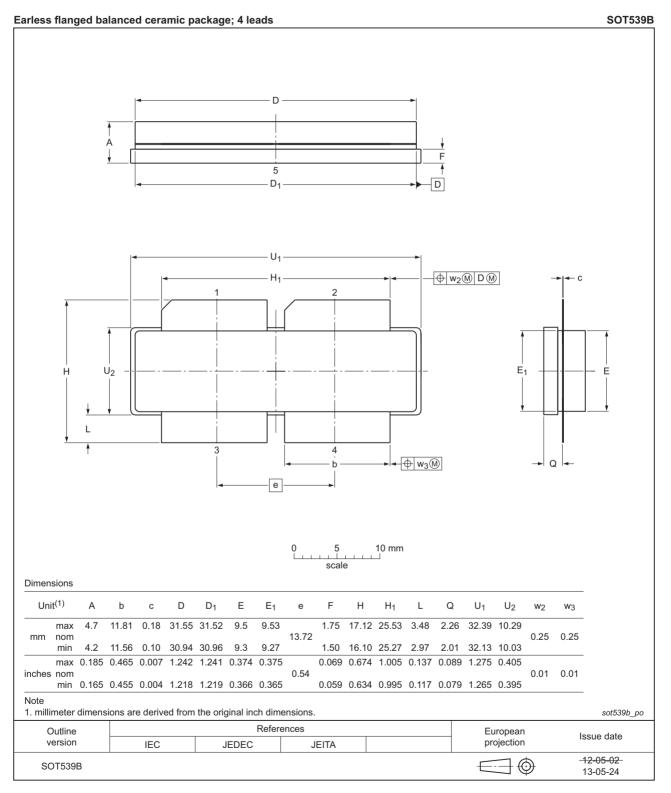


Fig 9. Package outline SOT539B

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10.	Abbreviations
Acronym	Description
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLU6H0410L-600P_6H0410LS-600P#3	20150901	Product data sheet		BLU6H0410L-600P_6H0410LS-600P v.2	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLU6H0410L-600P_6H0410LS-600P v.2	20130712	Product data sheet	-	BLU6H0410L-600P_6H0410LS-600P v.1	
BLU6H0410L-600P_6H0410LS-600P v.1	20120426	Product data sheet	-	-	

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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